# EURO QUARTZ

# CMOS SMD TCXO 7.0 x 5.0mm

## 1.5ps phase jitter

- Quick turnaround, low-cost TCXO
- Standard 7.0 x 5.0 x 2.5mm SMD package
- Supply voltage 2.5V or 3.3 VDC
- Frequency stability from ±1ppm over -40 to +85°C

## DESCRIPTION

(V)EMQF574T series TCXOs are packaged in a miniature, 3.2 x 2.5mm outline, ceramic SMD package. With squarewave (LVCMOS) output, tolerances are available from  $\pm 1.0$ ppm over -40° to +85°C. The part exhibits low supply current, 25mA typ. at 50MHz.

## SPECIFICATION

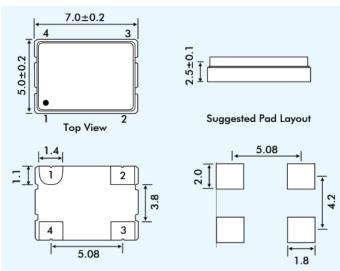
Product Series C					
	TCXO:	EMQF574T			
	VCTCXO:	VEMQF574T			
Frequency Range		10.0MHz to 245MHz			
Output Wavefor	m:	Squarewave, LVCMOS			
Phase jitter rms					
	12kHz to 20MHz: 1.875MHz to 20MHz:	1.5ps typical <400fs			
Initial Calibration	n Tolerance:	<±1.0ppm at +25°±2°C			
Operating Temp Frequency Stabil		from 0°~50° to -40°~+85°C			
	nperature:	±2.5ppm over -30 to 85°C (Default)			
		±0.5ppm over -30 to 85°C (Available)			
		±1.0ppm over -40 to 85°C (Available)			
vs. Age	eing:	±1.0 ppm max. first year			
vs. Vol	tage Change:	±0.2 ppm max. ±5% change			
vs. Loo	nd Change:	±0.2 ppm max. ±10% change			
vs. Ref	low (SMD type):	±1.0ppm max. for one reflow			
		(measured after 24 hours)			
Supply Voltage:		+2.5VDC±5% or			
		+3.3Volts ±5%			
Output Logic Lev	vels:	Logic High: 90% Vdd min.			
		Logic Low: 10% Vdd max.			
Rise/Fall Times:		1.5ns typ. 3.0ns max.			
Duty Cycle:		50%±5% standard,			
Start-up Time:		5ms typical, 10ms max.			
Output Load:		15pF			
Current Consum	•				
at 50N		24mA typical			
at 125		28mA typical			
at 200		30mA typical			
Current Consum					
at 50N		26mA typical			
at 125		30mA typical			
at 200	MHz:	34mA typical			

## 10MHz to 245MHz



EMQF574T

## **EMQF574T - OUTLINES AND DIMENSIONS**



### **Pad Connections**

1 No connection for TCXO / Voltage control for VCTCXO

2 Ground

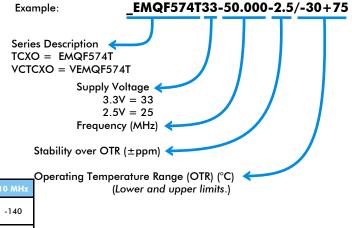
3 Output

4 Supply Voltage

## **VEMQF574T VOLTAGE CONTROL SPECIFICATION**

#### Control Voltage Vdd = +2.5V:Vcon centre = +1.4V Vdd = +3.3V:Vcon centre = +1.5VV Control Range Vcon range = $+1.4V \pm 1.0V$ Supply = +2.5V: Vcon range = $+1.5V \pm 1.0V$ Supply = +3.3V: Frequency Pulling Range: ±8 ppm min. **Slope Polarity:** Positive (increase of control voltage increases output freq. Linearity: $\pm 5\%$ typical $\pm 10\%$ max. Input Impedance: $1M\Omega$ typical Modulation Bandwidth: 10kHz min. measured at +3dB

## PART NUMBERS



### SSB PHASE NOISE at 25°C

c	Offset		10Hz	100Hz	1kHz	10kHz	100kHz	1 MHz	10 MHz
VMQF326 156.25MH		(dBc/Hz)	-57	-94	-105	-112	-113	-134	-140
RMS Jitter		1.5ps (12kHz to 20MHz integrated)							

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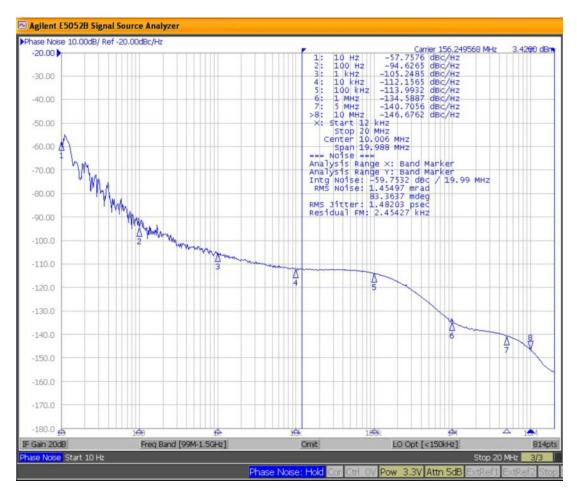
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# CMOS SMD TCXO 7.0 x 5.0mm

## **ENVIRONMENTAL PERFORMANCE SPECIFICATIONS**

Status:	RoHS Compliant, Pb (lead) free in accordance with EU Directive 2002/95/EC 6/6(2002/95/EC) and WEEE (2002/96/EC)		
Moisture Sensitivity:	Level 1 (infinite) according to IPC/JEDEC J-STD-020D.1		
Second Level Interconnect:	e4		
Storage Temperature Range:	-55° to +125°C		
Humidity:	85%RH, 85°C, 48 hours		
Fine Leak / Gross Leak:	MIL-STD-202F method 1014, condition A / MIL-STD-883, method 1014, condition C		
Solderability:	MIL-STD-202F method 208E		
Reflow:	260°C for 10s, x2		
Vibration:	MIL-STD-202F method 204, 35g, 50 to 2000Hz		
Shock:	MIL-STD-202F method 2133B, test condition E, 1000g <sup>2</sup> <sup>1</sup> / <sub>2</sub> sinewave		
Resistant to Solvents:	MIL-STD-202F method 215		
Temperature Cycling:	MIL-STD-883 method 1010		
ESD Rating:	Human Body Model (HBM): 1500V min.		
Pad Surface Finish:	Gold (Au) 0.3µm to 1.0µm over nickel (N) 1.27µm to 8.89µm		
Weight of device:	0.045gm typical		
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## PHASE NOISE PLOT OF VMQF574P33-156.250MHz



## EMQF574T

10MHz to 245MHz